1. Hribšek Den. of El. Engineering University of Belgrade Belgrade, Yugoslavia

R.W. Newcomb Dep. of El. Engineering University of Maryland College Park,Md.20742 USA

THE SCATTERING MATRIX OF A SAY SECTION

ABSTRACT- The scattering and transfer scattering matrices are determined as a function of frequency for !! equal basic SAM sections. This uses a previously determined equivalent circuit which was analysed on chain and admittance matrix basis. These results allow for a general but cuite practical formulation of a theory for SAM circuits including coverage of multiport SAM devices.

1. INTRODUCTION

In the last decade considerable work has been done in the surface accustic wave field, starting from the theory and principles of operation to the design and fabrication techniques. It has been shown that in the design of SAY devices a circuit model representation is its cornerstone. Especially a frequency domain equivalent circuit model [1,2,3] has proven remarkably successful [2], in characterizing the exitation and detection of surface waves. Usually only the transfer characteristic and input admittance at the electric port of the interdigital transducer, as a vital part of every SA! device, are determined - using chain and admittance matrix analysis of the equivalent circuit. However, the reflections at acoustical and as well, at the electrical port are also of vital importance. There are some papers [3, 4] dealing with reflection coefficients but only at the synchronious frequency. In this paper the scattering and transfer scattering matrices of a SAV device section are determined as a function of frequency. The starting point is the equivalent circuit of a basic one electrode pair section in the most memeral case of the ratio of the electrode width and snacing. Using the previous chain and admittance matrix results the scattering and transfer scattering matrices of H equal basis sections are determined.

2. REVIEW OF EQUIVALENT CIRCUIT SECTION AND SCATTERING MATRICES

The basic structure of a SAU device is one electrode pair section as shown in Fig. 1. Its equivalent nodel with one electric and two acoustic ports is given in Fig. 2 [1]. The acoustic variables are the velocities and the forces v_1 v_2 , v_3 , v_4 , v_5 , and the electric ones are v_3 and v_3 . The relationship between the variables is given by:

$$(2) \quad 1 = \begin{bmatrix} v_1 \\ v_2 \\ 1_3 \end{bmatrix} \qquad \qquad V = \begin{bmatrix} F_1 \\ F_2 \\ v_3 \end{bmatrix}$$

and according to [1]:

(3)
$$[y] = \begin{bmatrix} y_{11} & y_{12} & y_{13} \\ y_{12} & y_{11} & y_{13} \\ y_{13} & y_{13} & y_{13} & y_{13} \end{bmatrix}^{i-1}$$

(4)
$$y_{11} = \frac{1}{jZ_C}$$
 $\frac{\cos \theta - \sin \theta}{\sin \theta + 2\pi(\cos \theta - 1)}$

(5)
$$y_{12}^2 = \frac{3}{Z_c} \frac{1 - y \sin \theta}{\sin \theta + 2y(\cos \theta - 1)}$$

(6)
$$y_{13} = \frac{j\psi}{Z_c} = \frac{\cos \theta - 1}{\sin \theta + 2\psi(\cos \theta - 1)}$$

(7)
$$y_{33} = j\omega C_0 \left[1 + \frac{2k^2}{\theta} + \frac{1 - \cos \theta}{\sin \theta + 2\pi(\cos \theta - 1)} \right]$$

(8)
$$\phi^2 = 2k^2 c_0 Z_c v/\gamma \lambda_0$$

(9)
$$\theta = \omega \gamma \lambda_0 / 2 \gamma = \gamma_{\parallel} \frac{\omega}{\omega_0}$$

$$(10) \ Y = \alpha \frac{k^2}{\theta}$$

(11)
$$Z_c = Z_0 (1-\beta k^2)$$
 , $Z_c = \rho vA$

(12)
$$C_S = \frac{C_0}{\alpha \phi^2}$$

(17

wh

where: p = density of the substrate

A = cross section area

v = sound velocity

k = electromechanical counting constant

< = turns ratio of an acoustic-to-electric circuit transformer

and if are the functions of the ratio $(L_1-S_1)/S_1$, and i denotes the position of the particular electrode pair.

It should be nointed out that the section and its conivalent mode, are concernity valid for any ratio of electrode width L_1+D_2 and electrode specima G_1 [1].

It is well known [b] that the scattering matrix % of a network characterized by its admittance matrix Y can be determined as:

(13) $S = 1_3 - 2Y_p$

where Y_{α} is the admittance matrix of the summerted network which is shown in Fig. 3.

Using "1=12=23=1, Ya can to found es:

(14) $Y_a = Y(1_3 + Y)^{-1}$ Substituting (14) into (13) we get:

(15) $1 = 1_2 - 2x(1_2 + y)^{-1}$

The transfer scattering matrix T, defined as in [5], can be expressed in terms of the $S_{i,j}$'s of the S matrix as follows:

3) THE SCATTERING MATRICE'S FOR SAY SECTIONS

The coal of this paper is to determine the scattering and transfer scattering matrix of a SMV structure consisting of H equal hasic sections connected as shown in Fig.4a. To be able to achieve it, as can be seen from (15) and (16), we can find the admittance of the whole structure. According to Fig.4a and (3), (4), (8) and (6) we find:

(17)
$$\begin{bmatrix} F_n \\ v_n \end{bmatrix} = q \begin{bmatrix} F_{n-1} \\ v_{n-1} \end{bmatrix} + \begin{bmatrix} -y_{13}/v_{12} \\ y_{13}y_{22}/y_{12}-y_{13} \end{bmatrix}$$
 y_3

where:

$$(18) 4 = \frac{1}{1 - \psi \sin \theta} \begin{bmatrix} \cos \theta - \psi \sin \theta - jZ_{c}(\sin \theta + 2\psi \cos \theta - 2\psi) \\ -jZ_{c}^{-1} \sin \theta \cos \theta + \psi \sin \theta \end{bmatrix}$$

Taking into account the basic sections in Fig.4a are connected accoustically in cascade and electrically in parallel, and that y_{31} and y_{32} in alternating sections have onnesite signs (3), we get:

(19)
$$\begin{bmatrix} F_{R} \\ v_{N} \end{bmatrix} = q^{N} \begin{bmatrix} F_{1} \\ v_{1} \end{bmatrix} + y_{13} \begin{bmatrix} iZ_{c} sinN\delta sin\delta(sin \alpha)^{-1/2} \\ -cosN\delta(1-\psi sin \alpha)^{-1} - (-1)^{N-1} \end{bmatrix}$$

where & is defined by:

(20)
$$\sin \varepsilon = (\sin \theta + 2\psi \cos \theta - 2\psi)^{1/2} (1 + \psi \sin \theta)^{-1} (\sin \theta)^{1/2}$$

Diagonalizing $\mbox{\sc u}$ using a unitary transformation the product is seemed to be:

(21)
$$y^{N} = (1 - \psi \sin \theta)^{-1} \sin N\delta \begin{bmatrix} \cot \eta N\xi & -jZ_{c}(\sin \theta)^{-1/2} & \sin \delta(1 - \psi \sin \theta) \\ -jZ_{c}^{-1}(\sin \theta)^{-1/2} \\ \hline \sin \delta(1 - \psi \sin \theta) \end{bmatrix}$$
 cotons

Now, using (21) the admittance matrix Y of the whole structure shown in Fig. 4a and defined according to Fig. 4b can be calculated as follows:

$$\frac{-j\cot N\delta}{Z_{c}(1-2\psi t_{3}\frac{\theta}{2})^{1/2}} = \frac{\frac{j(1-\psi \sin \theta)}{Z_{c}\sin N\delta(1-2\psi t_{3}\frac{\theta}{2})^{1/2}} \frac{y_{13}}{Z_{c}(1-2\psi t_{3}\frac{\theta}{2})^{1/2}} = \frac{\frac{j(1-\psi \sin \theta)}{Z_{c}(1-2\psi t_{3}\frac{\theta}{2})^{1/2}}{Z_{c}(1-2\psi t_{3}\frac{\theta}{2})^{1/2}} \frac{(-1)^{N-1}y_{13}}{(-1)^{N-1}y_{13}}$$

where y_{13} and y_{33} are given by (6) and (7).

Substituting (22) into (15) we can calculate Sij's and, therefore, T at any frequency. The calculation is straightforward but the use of a computer is helpful since the expressions are rather bulky.

4. DISCUSSION

In the above we have determined the scattering and transfer scattering matrices of SAL sections using the equivalent circuit available in the literature. It can be seen that the cases discussed by Smith, et al. in [3, p. 850] are only the special cases of S_{11} and S_{12} when $S_{2}=R_{1}=R_{1}$, f=f, $R_{3}=f$, and $R_{12}=0$ ("cross-field"nodel or $\alpha=1$ ("In line" model).

Of particular importance are the 2-port nurely methanical transfer scattering matrices since these simply multiply when SAW sections are cascaded.

5. REFERENCES

- [1]. H. Mathews, ed. "Surface Nave Filters", ch. 2, John Miley, New York, 1977.
- [2]. A.A. Oliner, ed: "Acoustic Surface Maves", ch. 3, Springer-Verlag, Ferlin, 1978.
- [3]. V.R. Smith, "Analysis of Interdigital Surface Pave Transducer by Use of Equivalent Circuit Model", IEEE Trans. on Microvave Theory and Techniques, vd. "TT-17, Mo. 11, Mov. 1960, pp. 256-264.
- [4]. B. M. Gerard, "Acoustic Scattering Parameters of the Electrically Loaded Interdinital Surface Maye Transducer", IEEE Trans. on MIT, vd. MIT-17, Fo. 11, Fov. 1965, ap. 1045-1046.
- [5]. R.H. Hewcomb, "Linear Multiport Synthesis", p. 02, "cGraw Hill, New York, 1966.

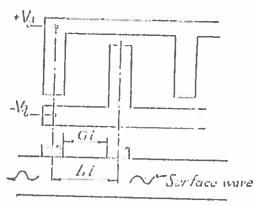
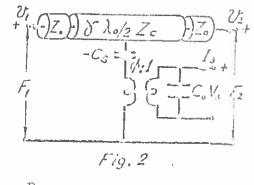
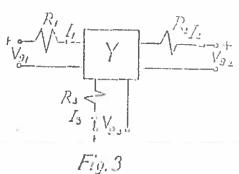
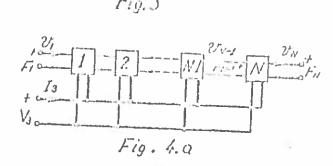
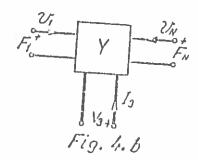


Fig. 1









YU ISSN 0351-1669

YUGOSLAV SOCIETY FOR ELECTRONICS AND AUTOMATION (ETAN) and FACULTY OF ELECTRICAL ENGINEERING, THE UNIVERSITY »EDVARD KARDELJ« OF LJUBLJANA

PROCEEDINGS
OF
THE
THE
FOURTH
INTERNATIONAL
SYMPOSIUM
ON
NETWORK
THEORY

LJUBLJANA, YUGOSLAVIA SEPTEMBER 4-7, 1979.